NSN 5961-00-470-8291

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-470-8291 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.620 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, dc **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**